# Schrodinger equation for current carrying states

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# Abstract

Schrodinger equation with given, a priori known current is formulated. A non-zero current density is maintained in the quantum system via a subsidiary condition imposed by vector, local Lagrange multiplier. Constrained minimization of the total energy on the manifold of an arbitrary current density topology results into a non-linear self-consistent Schrodinger equation. The applications to electronic transport in two-term inalm olecular devices are developed and new macroscopic de nition of a molecular current-voltage characteristic is proposed. The Landauer form ula for the conductance of an ideal one-dimensional lead is obtained within the approach. The method is exam ined by modeling of current carrying states of one-dimensional harm onic oscillator.

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#### I. IN TRODUCTION

The remarkable miniaturization of conventional microelectronic devices has been witnessed over the last decades. If the miniaturization trend is to continue, elements of microelectronic circuits, e.g. transistors and contacts, will soon shrink to single molecules or even atom s. In the past few years, there have been considerable advances towards fabrications and experimental studies of mono-molecular electronic devices [1]. This activity has been largely spurred on by development of experimental techniques to form atomic scale electrical contacts such as scanning tunneling microscopy [2] and mechanically controllable break junctions [3]. Measurements of current-voltage (I-V) characteristics have been recently performed on a single benzene-1,4-dithiolate molecule [4], buckminsterfullerene [5], individual atoms [6], nanoclusters [7] and carbon nanotubes [8]. These initial observations of conduction in molecules were followed quickly by experimental demonstration of the simplest devices: molecular diodes [9], switches [10] and memory elements [11] although molecular equivalent of a transistor is yet to be discovered.

Several theoretical approaches have been recently developed to describe electronic conductivity of m olecules [12]. One of the widely used methods is based on the combination of extended Huckelm odel or density functional theory to treat the molecular electronic structure, an electronic reservoir model for the contacts and linear response approximation to compute the electronic current as a function of the applied voltage [13, 14, 15, 16, 17]. The m ost recent applications used Lippm ann-Schwinger or non-equilibrium Green's functions form alism splus \ jellium " m odel for the contacts and for the m olecular-contact interactions [18, 19]. In all these approaches, the system is partitioned into three parts: molecular wire and two electron reservoirs to represent m etallic contacts. The use of the m odel dependent reservoir-molecule interaction as one of the most pivotal ingredient dim inishes the ability of these methods and prevents from a development of predictive and quantitative techniques for the electronic transport problem . Recent density functional theory based calculation dem onstrates that a molecular wire is bonded to a gold contact by the thiol bridge which is known to be the strong covalent interaction [20]. The empirically treated coupling between m etal contacts and the m olecular wire, which serves as the interaction for the linear response calculations and represents the kernel of the corresponding Lippm ann-Schwinger equation, is at least strong as interm olecular interaction. Recent papers also indicate the exact nature

of the molecule-contact bonding is critical in predicting the correct order of magnitude for the current with applied bias [18].

The miniaturization shrinks the size of the system to a level when the problem can be addressed by ab initio electronic structure methods. As an example consider a standard prototype m olecular device system with a single benzene-1,4-dithiolate m olecule covalently bonded to two gold electrodes [4]. The problem can be reduced to the system where the molecule is bonded to two smallAu clusters [17]. A gold cluster with reasonably smalledge in uence on the molecular-surface bonding contains 10 atoms [20]. With a single benzene-1,4-dithiolatem olecule as them olecular wire the contact-wire-contact system consists of just 32 atom s. System s of such size can be routinely simulated by standard quantum chem istry codes. The main obstacle for the application of the st principle electronic structure methods is not the size of the system but modeling of the electronic current and interpretation of the applied voltage. Suppose that we have solved Hartree-Fock or Kohn-Sham equations for a molecular device. The ground state wave function is real in absence of a magnetic eld and therefore the current density computed from this wave function is zero everywhere in the sample. Another important issue is an interpretation of the applied voltage. Virtually all present theoretical approaches are pivotally relied on simpli ed, noninteracting electrons type m odels for the m etal contacts where the external voltage bias can be straightforw ardly associated with the Ferm i energies shift between left and right electronic baths. One of the reasons for use electronic reservoir models to represent the metallic contacts is principle theoretical di culties related to a rigorous quantum mechanical de nition of the applied voltage.

In this paper, we advocate an alternative approach where the use of the electronic reservoir to m odel contacts is completely avoided from the very beginning and a quantum system with current is treated electively as a closed system. We begin by describing the variational principle for a quantum system with current. We then derive the Schrodinger equation with probability ux which provides exact wavefunctions on the manifold of a given current density. We next specify two-term inalm olecular device steady current subsidiary condition and develop the Schrodinger equation for a two-term inalm olecular device. We discuss the use of the energy ballance condition to compute current-voltage characteristics of quantum system s. We then derive the Landauer form ula for non-interacting charge carriers within the form alism. Finally, we demonstrate the salient features of the approach through the

num erical solution of the self-consistent Schrodinger equation for one-dimensional harm onic oscillator with constrained current.

II. SCHRODINGER EQUATION W ITH PROBABILITY CURRENT

### A. Variational principle

W e start with the nonrelativistic H am iltonian for a particle in the external scalar potential v(r) (atom ic units are used throughout the paper unless otherw ise mentioned):

$$H = \frac{1}{2}r^{2} + v(r) :$$
 (1)

W e de ne density and param agnetic current density as:

$$(\mathbf{r}) = (\mathbf{r}) \quad (\mathbf{r}) \tag{2}$$

$$j(\mathbf{r}) = \operatorname{Im} f \quad (\mathbf{r})\mathbf{r} \quad (\mathbf{r})g \tag{3}$$

where (r) is not generally an eigenvector of the H am iltonian H. W e will specify an eigenproblem for the (r) in the next section. The physical current is equivalent to the param agnetic current densities in absence of an external magnetic eld.

An eigenvector for a bound state of a real H am iltonian can be always made real by a change of the phase of the wave function. The H am iltonian H is real therefore if we just solve standard Schrödinger equation with the H am iltonian H, we will obtain real wave function (r) and the current density j(r) will be automatically zero. The standard way to get a complex wavefunction out of a real H am iltonian is to assume certain boundary conditions. These boundary conditions could be an assumption of an incoming plane wave in scattering theory or periodic boundary conditions for a translationally invariant system. To solve a scattering problem for a molecular device is possible only at the cost of major unphysical approximations, e.g. via considering the molecular device as a singe scattering center. A nother approach is to assume periodic boundary conditions. The periodic boundary conditions prevent one from studying any situations where the change of chemical potential across the system is of nite magnitude because the chemical potentialm ust be also periodic in space. The local chemical potential is the decreasing function in the direction of the current and therefore the system can not be treated as translationally invariant at least along the current axis.

We have developed an alternative approach where a current carrying quantum system is treated e ectively as a closed system with a subsidiary condition for the generally discontinuous current density distribution. We start our derivation with the assumption that current carrying states of an open quantum system can be described in terms of wave functions of an e ectively closed quantum system if the current is maintained via explicit constraint. This assumption is a simplied, particular case of the standard assumption in statistical mechanics: a system coupled to a thermal bath can be described with statistical ensembles of a closed system in which the system -bath interaction is not explicitely considered, but enters only via Lagrange multipliers and subsidiary constraints. It has been recently demonstrated that a steady current open mesoscopic system can be described in terms of an ensemble of carrier states in the closed mesoscopic device itself if the steady current is additionally constrained [21, 22].

W e require that the current density is constrained to be specified function I(r). It results in the subsidiary constraint equation:

$$j(r) = 0$$
: (4)

The expression (4) generally can not be obtained by dimension of functional of and with respect to r. It means that the constraint eq.(4) is nonholonom in [23]. The variational problem is to minimize the total energy with respect to subject to the nonholonom in constraint for the current density (4). Two types of treatment are possible: we can either choose (r) in which the constraint is implicit or we can impose the constraint explicitly by using the Lagrange multiplier. We will follow the second approach which was recently suggested by K osov and G reer [24], elimination the part of the wavefunction by imposing the explicit constraint. A line of the constraint form ulated as eq.(4) is vector and nonholonom in it can be included into a variational functional via pointwise, vector Lagrange multipliers a (r) [24].

W ithin the Lagrange multiplier approach the constraint is explicitly achieved via introduction of the auxiliary functional:

$$[] = h \# ji E (h j i 1) a(r) (j(r) I(r)) dr: (5)$$

The rst two terms are standard in the variational derivation of the Schrodinger equation with the rst giving the total energy and the second is introduced to maintain the norm alization of the wave function. The third term with the vector Lagrange multipliers a (r) has been introduced to impose the subsidiary constraint for the current density.

A use of the variational principle can be justiled only for closed quantum systems. The choice of I(r) can not be obviously completely arbitrary to maintain the closed system boundary condition. The localized in space quantum system will be considered closed if, rst, there are no in- and out-probability ows in the system; and, second, if the wave function is an eigenvector of a Herm itian operator (it prevents the complex eigenenergies and therefore electively closes the system). We will demonstrate in the next section that both these conditions are satis ed within our approach.

#### B. Self-consistent Schrodinger equation

The minimization of the total energy subject to the subsidiary constraint for the current density (4), i.e the variation of the auxiliary functional [], results into the following non-linear Schrödinger equation:

$$\frac{1}{2} + v(r) = \frac{1}{2i} [a(r); r]_{+} \quad (r) = E \quad (r) :$$
 (6)

The anti-com mutator term ,

$$\frac{1}{2i} [r; a(r)]_{+} = \frac{1}{2i} (r a(r) + 2a(r)r);$$
(7)

is the additional completely in aginary potential arising directly from the constraint on the current density (consult with appendix A for the corresponding functional derivatives). This additional constraint potential forces the wave function (r) to be irrem ovably complex and insures that (r) produces the required current density I(r).

A physical interpretation of the Lagrange multiplier a(r) can be made more explicit if we rewrite eq.(6) in the following form :

$$\frac{1}{2}(ir a(r))^{2} + \frac{1}{2}a(r) a(r) + v(r) (r) = E(r):$$
(8)

It can be now established that the current constraint has introduced the term s which are mathematically equivalent to an external vector potential. But unlike an external vector potential, the Lagrange multiplier a (r) does depend upon the wave function (r) and eq.(8) becomes nonlinear and must be solved self-consistently. The eigenvalue problem eq.(8) is generated by Herm it ian operator since the Lagrange multiplier a (r) is real. Being a solution of the Herm it ian eigenproblem the eigenenergy E is real and the wavefunctions form a complete set in Hilbert space. W ithin our approach we deal with the localized in space system with the wave functions generated by the herm it ian eigenproblem (8). Such system is by de nition closed and therefore the use of the variational principle is form ally justi ed.

The Schrödinger equation with current (8) is not yet in a form allowing for a solution to be found as the Lagrange multiplier a (r) is not known yet. We next seek a solution for the Lagrangian multiplier a (r). In the developing of this method we have found out that the most signi cant source of numerical instabilities in the solution of the nonlinear Schrödinger equation (8) arises from the determination of the Lagrange multiplier a (r). The described below procedure obtaining of the Lagrange multiplier has been found to be the most robust. Multiplying eq. (6) from the left on the (r) and subtracting from the obtained equation its own Hermitian conjugate, yields

$$r j(r) = r (a(r) (r))$$
: (9)

Equation (9) can be resolved for a (r) with the assumption that both the density (r) and the current density j(r) decay to zero at in nity. In this case the direct integration of eq.(9) results into the following expression for the Lagrange multiplier a (r):

$$a(\mathbf{r}) = \frac{\mathbf{j}(\mathbf{r})}{(\mathbf{r})} \tag{10}$$

Substitution of the constraint for the current density eq.(4) into eq.(10) yields the simple expression in which the Lagrange multiplier depends upon the wave function only via the density in the denom inator:

$$a(r) = \frac{I(r)}{(r)}$$
(11)

There is a direct similarity between equation for the Lagrange multiplier (10) and the de nition of the velocity of a quantum trajectory within de Broglie-Bohm causal description of quantum mechanics [25]. Within the de Broglie-Bohm dynamics the velocity u (r;t) of a trajectory at a given point is computed as [26]:

$$u(\mathbf{r};t) = \frac{j(\mathbf{r};t)}{(\mathbf{r};t)}; \qquad (12)$$

therefore, at least for stationary systems the vector Lagrange multiplier a (r) can be directly related to the velocity for a corresponding de Broglie-Bohm trajectory. By this analogy we can make the physical interpretation of the Lagrange multiplier more explicit. In the de Broglie-Bohm quantum dynamics to maintain the constant ux at the given density prole one needs to adjust the local trajectory velocities. The vector Lagrange multiplier appears to play the simular role in the Schrödinger equation with constrained current. Likew ise for a point with the non-zero trajectory velocity, the current density has nite value at a point with the non-zero vector Lagrange multiplier. And likew ise the de Broglie-Bohm velocity, a product of the vector Lagrange multiplier on the probability density yields the current density.

W ith this choice of the Lagrange multiplier (11) we obtain the Schrödinger equation with the current I(r) in the self-consistent and closed form :

$$\frac{1}{2} \quad \text{ir} \quad \frac{I(\mathbf{r})}{(\mathbf{r})}^{2} + \frac{1}{2} \frac{I^{2}(\mathbf{r})}{(\mathbf{r})^{2}} + \mathbf{v}(\mathbf{r}) \quad (\mathbf{r}) = \mathbf{E} \quad (\mathbf{r}) :$$
(13)

The derivation of the self-consistent Schrödinger equation eq.(13) composes one of the central results of the paper.

III. SCHRODINGER EQUATION FOR A TWO TERM INAL MOLECULAR DE-VICE

The desire to develop the basic Schrodinger equation for calculations of I V characteristics of two term inalm olecular devices is the impetus for the present study. To achieve this aim, we specify the molecular wire constraint on the current density:

$$dy dz j_{x} (r) = I_{x} (x L; R x); \qquad (14)$$

where  $I_x$  is the steady current through the molecular device. The step function,

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$$(x L; R x) = (x L) (R x);$$
 (15)

equals to 1 if L = x R and zero otherwise. L and R are the left and right boundaries for the molecular device. W ithin this description, net current ow is aligned along the x axis and there are no in- and out ow : the current starts at the left boundary L and completely absorbed at the right R.W ith this constraint it is not required to x the full vector j(r) everywhere in the sample. Only the net current ow across a cross section  $R^{0}$  dy dz  $j_{x}(r)$  is constrained, and this quantity is readily available experimentally. This is a simple geometric arrangement to specify current ow for the two term in almolecular device and can be extended to more complex device topologies, e.g. for the three term in al devices where three tips are connected to a single molecule [27].

Likewise, as for the derivation of the exact Schrodinger equation in the preceding section, with this choice of the constraint (14) the minimization of the auxiliary functional (5) now yields the Schrodinger equation for the steady current two terminalmolecular device:

$$\frac{1}{2} + v(r) \qquad \frac{1}{2i} a_x(x); \frac{0}{0x} (r) = E (r):$$
(16)

The expression for the Lagrange multiplier given by eq.(11) can be straightforwardly extended to the steady current molecular device, with the result is

$$a_{x}(x) = \frac{I_{x}}{y_{z}(x)} (x \quad L; R \quad x); \qquad (17)$$

where we have introduced the quantity

$$Z_{yz}(x) = dydz (r):$$
(18)

W ith the expression for the Lagrange multiplier  $a_x(x)$  in hands, we can complete the Schrodinger equation for the two-term inal molecular device with steady current  $I_x(x)$ 

$$\frac{1}{2} + v(\mathbf{r}) \qquad \frac{\mathbf{I}_{\mathbf{x}}}{2\mathbf{i}} \qquad \frac{(\mathbf{x} \quad \mathbf{L}; \mathbf{R} \quad \mathbf{x})}{\mathbf{y}_{\mathbf{z}}(\mathbf{x})}; \frac{\mathbf{\theta}}{\mathbf{\theta}_{\mathbf{x}}} \qquad (\mathbf{r}) = \mathbf{E} \quad (\mathbf{r}): \qquad (19)$$

Some aspects of eq.(19) deserve special discussion. The imaginary potential which enforces the wave function to produce steady current  $I_x$  depends upon the x coordinate only. The range of this potential is restricted by the molecular device boundaries. One of the term s in this potential is proportional to the derivative of the step function,

$$\frac{\theta}{\theta x} (x L; R x) = (x L) (x R); \qquad (20)$$

and therefore yields the singular in aginary -function potential on the device boundaries. It is known from the standard quantum mechanics textbooks [28] that a -function potential results in the discontinuity of the rst derivative of the corresponding solutions of the Schrodinger equation. Likewise, the in aginary component of the eigenfunction (r) of the Schrödinger equation for a molecular device (19) has the discontinuous rst derivative at the points x = L and x = R.

The nalcomment regarding the computation of the I-V characteristic of a two-term inal m olecular device is in due order. The current carrying states obtained as the solutions of the m olecular device Schrodinger equation (19) must now be associated with current-voltage characteristics available experimentally. The rigorous de nition of the applied voltage is a controversial issue if one does not invoke to noninteracting electron reservoirs to represent contacts. W e propose the following macroscopic de nition of the applied voltage which has the direct relation with the quantities measured experimentally. The energy increase from the applied voltage U is computed by the numerical integration with an assumption of linear voltage drop between the left and right boundaries:

$$E_{d}(U) = \frac{U}{R L} \int_{L}^{Z^{R}} dx (R x)_{yz}(x) :$$
 (21)

We compute the energy of the non-active, i.e. with zero current, molecular device and compute the total energy of the same molecular device at an experimentally given current  $I_x$ . Then the energy increase for the establishment of the current carrying state, i.e. the energy dierence

$$E_{d}(I_{x}) = E_{d}(I_{x}) \quad E_{d}(I_{x} = 0)$$
 (22)

is calculated. Because of the energy ballance condition the  $E_d(U)$  must be equal to the  $E_d(I_x)$  and it results into the following equation for the applied voltage bias:

$$U = \frac{(R \ L)}{\underset{L}{\mathbb{R}}} E_{dx}(I_{x}) : \qquad (23)$$

The eigenenergy E of the Schrödinger equation (19) should not be confused with the energy of m olecular device. The eigenenergy E serves only as the Lagrange multiplier to enforce orthogonality of the wave function. The energy of the molecular device can be obtained as an expectation value of the real physical H am iltonian H with the integration restricted by the molecular device region:

$$E_{d}(I_{x}) = \frac{Z}{dydz} \frac{Z^{R}}{dx} (r) \frac{1}{2} + v(r) (r); \qquad (24)$$

where (r) is the solution of the Schrödinger equation (19) with the given  $I_x$ . Since the wavefunction (r) is complex and the integration (24) is not performed over whole space, it is not obvious from the expression (24) that the device energy  $E_d(I_x)$  must be real. We will show now that the device energy  $E_d(I_x)$  is real if the wavefunction (r) produces the constrained current density (14). To prove this we subtract from eq.(24) its own complex conjugate and after a bit of algebra arrive to the following expression:

$$Z \qquad Z^{R} \qquad I$$

$$E_{d}(I_{x}) = i \quad dydz \quad dxr \quad j(r) = i \quad dSn \quad j(r): \qquad (25)$$

$$L$$

The length of the quantum wire is aligned along the x axis and the surface integral does the integration over the surface of the rectangular box with one y z face at x = L, another y z face at x = R and any of the x y or x z faces are removed at the in nity. W ithin our constraint, there is a positive current owing into the y z face at x = L and exactly the same positive current owing out of the y z face at x = R. There is no current ow out of the region in any of the x y or x z faces. Therefore the surface integral vanishes I

$$dSn j(r) = 0$$
 (26)

and the device energy  $E_d(I_x)$  de ned via eq.(24) becom es real.

#### IV. EXAMPLE CALCULATIONS

## A. Conductance of an ideal one-dim ensional lead

In order to establish connection with standard approaches and test the m ethod we derive the Landauer form ula [29] using the Schrodinger equation for current carrying states eq.(13) as the starting point. Consider noninteracting electrons m oving along a one-dimensional wire without any scatterer. The electronic density does not depend upon x yielding the following Schrodinger equation with steady current I:

$$\frac{1}{2}\frac{d^2}{dx^2} + i\frac{I}{dx}\frac{d}{dx} = E_{k-k}(x) :$$
 (27)

Equation (27) has the plane-wave solution

$$_{k}$$
 (x) exp (ikx) (28)

with eigenenergy

$$E_{k} = \frac{k^{2}}{2} \quad \frac{Ik}{I} : \qquad (29)$$

The sim ilar dispersion relation as given by eq.(29) has been obtained within the same approach for uniform electron gas with applied direct current [24]. For the small voltage and tem perature transm issions of electrons take place only through the states in close vicinity of the Ferm i level. There are two vectors k, one is positive and one is negative, which correspond to the Ferm i energy:

$$k_{+} = \frac{I}{-} + \frac{S}{2E_{F}} + \frac{I}{-}^{2}; \qquad (30)$$

$$k = \frac{I}{2E_{F}} + \frac{I}{2}^{2}$$
 (31)

Following the Landauer approach we associate the voltage drop (at the zero tem perature) with the gap between the singe-electron energies of the electrons moving in the direction of the current (k > 0) and electrons moving in the opposite direction (k < 0):

$$U = \frac{k_+^2}{2} - \frac{k^2}{2} :$$
 (32)

Substituting the expressions for the  $k_+$  and  $k_-$  eqs.(30,31) into the Landauer's de nition of the applied voltage (32), we readily nd

$$I = GU ; (33)$$

with the conductance

$$G = \frac{r}{2 2E_{\rm F} + \frac{I}{2}^2} :$$
(34)

Then, the use of the standard relation between the Ferm im on entum  $k_F$  and the electronic density =  $k_F$  = along with the small current expansion of the square root eq.(34) results into the Landauer form ula for a single transport channel of an ideal one-dimensional lead [30]:

$$G = \frac{1}{2} :$$
 (35)

If we take into account the spin degeneracy of real electrons, the conductance becomes multiplied by 2. By accounting the degeneracy and converting the conductance eq.(35) to SI units the standard value  $G = e^2 = (h) = (12.9 \text{ K})^{-1}$  is obtained. Re-deriving the standard result we demonstrate that in the low current and zero temperature limits our method is equivalent to the traditional approaches which are based on the Landauer formula.

## B. Num erical solution of the Schrodinger equation with current

W e dem onstrate applications of the m ethod with num erical examples. The num erical solution of a self-consistent Schrodinger equation is often perform ed within a nite basis set expansion for the wave function with subsequent diagonalization of the H am iltonian m atrix until the self consistency is reached. W e have found out that it is com putational convenient to form the com plete, real basis set from the solutions of the zero-current Schrodinger equation:

$$\frac{1}{2} + v(r)$$
 (r) = " (r) : (36)

Then we expand the wave function of a current currying state on this basis

$$(r) = C (r);$$
 (37)

the coe cients C must be complex for the wave function which produces a non-zero current. W ith the expansion (37) we arrive to the following complex, Herm it ian eigenproblem :

X (" 
$$iw$$
 (I)) C = E C ; (38)

where the current dependent matrix element w (I) is computed in appendix B and is given by the following integral:

$$w (I) = \frac{1}{2} \int_{-\infty}^{Z} dr \frac{I(r)}{(r)} (m(r)r_{n}(r) - m(r)r_{m}(r)) : \qquad (39)$$

The matrix elements w (I) are real and depend on the expansion coe cients C via the density (r) thereby making the eigenvalue problem (38) nonlinear. The eigenproblem (38) is Herm it in because the matrix element w (I) changes its sign when we swap and indeces:

$$w (I) = w (I) :$$
 (40)

The num erical calculations were carried out for the one-dimensional system. With an eye on molecular device simulations we solve the self-consistent Schrodinger equation for the step function constraint as a primary example:

$$j(\mathbf{x}) = \mathbf{I} \quad (\mathbf{x} \quad \mathbf{L}; \mathbf{R} \quad \mathbf{x}) \tag{41}$$

The external potential was taken in the harmonic oscillator form and we put L = 2.0and R = 2.0 as left and right boundaries for the current carrying part of the system in all our calculations. Our basis set was built up from the 25 eigenvectors of the zero current Ham iltonian. The self-consistency was assumed to be achieved when the root mean square deviation of the wave function vectors of the two subsequent iterations was less then 10<sup>8</sup>.

First, we plot the Lagrange multiplier as a function of the coordinate on the gure 1. The Lagrange multiplier is discontinuous at the system boundaries. The Lagrange multiplier is vanishing out of the system region and it is the inverse function of the density (x) inside the system. As it can be expected from the analogy with the de Broglie-Bohm quantum hydrodynam ics (12) (the lower the density, the larger the local velocity) the Lagrange multiplier reaches its maximum values in the regions of depleted density and has the minimal value at the point of maxim al density.

In our next example we studied the deviation of the current carrying wave function (r) (I = 0.1) from the zero-current ground state wave function  $_0$  (r). The real component is depicted on the upper panel of the g2. The shape and magnitude of the real component do not undergo signi cant transform ation with the establishment of the current carrying state. A lthough the admixture of the higher term s in the expansion (37) results in the small damping oscillations on the tails of the real component of the wave function. The imaginary part of the wave function (plotted on the lower panel of the g2) is identically zero when the current is vanished. The imaginary component reaches its negative minimum at the left boundary L = 2.0 of the current carrying part of the system and then it discontinuously changes the sign of the rest derivative and undergoes alm ost linear increase until it reaches its maximum at the right boundary R = 2.0. When the coordinate x goes out of the non-zero current region the imaginary part of the wave function rapidly decays to zero value.

The establishm ent of the imaginary part of the wave function directly indicates the developm ent of the current carrying state. We studied transform ations of the imaginary com ponent as a function of the increased current. The imaginary components of the wave functions

are plotted on the g. 3 for three representative steady currents: I = 0.01, I = 0.5 and I = 0.1. At the very small current I = 0.01 the imaginary wave function is almost zero everywhere except the only small negative minimum at the left boundary and with the positive maximum at the right. The magnitudes of the imaginary component at the extremum s are nearly linearly proportional to the value of the constrained current. The slope of the imaginary component, i.e. the derivative, is always positive and almost constant between the left and right boundaries of the system. The imaginary part becomes zero when the real component reaches its maximum, i.e. at the point x = 0.0. A linearly the total wave function is real at the point x = 0.0 the current is not vanished because the derivative of the wave function remains complex.

Now we turn to the calculations of a \device" energy required to establish the current carrying state. Being the Lagrangian multiplier to maintain the wavefunction orthonorm ality, the eigenenergy E of the eigenproblem (38) is not directly related to the energy of the system. The energy increase due to the establishment of the current carrying state is de ned via the space restricted expectation value of the H am iltonian (24):

$$E_{d}(I) = \int_{L}^{Z^{R}} dx \quad (x) \quad \frac{1}{2} \frac{d^{2}}{dx^{2}} + v(x) \quad (x) = \int_{L}^{X} C C \quad (x) \quad (x$$

The table 1 contains the energy  $E_d(I)$  and the energy dimension between the nonactive, i.e. zero-current, and current I carrying state as a function of the increased current. The \device" energy is gradually increased with increasing current. As it can be deduced from the table 1, we need to pump into the system ' 0:14 au: of energy to establish the current I = 0:1 au: carrying state. A simple t of the data from the table 1 provides only the quadratic and cubic dependences of the \device" energy upon the steady current (for I 0:1):

$$E_{d}(I) = E_{d}(I = 0) + 17.4I^{2} \quad 36.5I^{3};$$
 (43)

thereby demonstrating that the term linear in the current has the m inor importance for the energetics of the current carrying quantum system and the main energy contribution comes from the  $I^2$  term. This energy dependence is generally agreed with the current-density functional theory of inhom ogeneous interacting electron gas where the current dependent correction to the standard exchange-correlation energy functional is also mainly proportional to  $I^2$  [31].

## V. CONCLUSIONS

In this paper, we have given a variational formulation of the Schrodinger equation with non-zero current. The Schrodinger equation with current is derived via a constrained minin ization of the total energy with a subsidiary condition for the current density. The subsidiary condition for the current density is maintained during the course of variation by a vector, pointwise Lagrange multiplier. An explicit elimination of this Lagrange multiplier results into the closed, self-consistent form of Schrodinger equation with current. We showed that the current carrying states are eigenvectors of the complex, Herm itian operator. The form ulation has been developed for general current density topologies and then speci ed for the case of a two-term in alm olecular device. We showed how the energy ballance condition can be used for rigorous computation of I-V characteristics of molecular devices: the energy increase due to the establishment of a current carrying state is associated with the applied voltage bias. We demonstrate the salient features of the approach by re-deriving the Landauer form ula for the conductance of an ideal one-dimensional lead and through a solution of the one-dimensional Schrodinger equation with xed current density. The complex, Herm itian m atrix was formed on a basis of the eigenvectors of the zero-current H am iltonian. The num erical solution was achieved via the self-consistent solution of the complex, Herm itian eigenproblem. We found out that a basis set form ed from the zero current Ham iltonian eigenvectors provides a robust algorithm for the self-consistent convergence. Our method has the great com patability with standard electronic structure methods which are also based on a variational principle e.g. Hartree Fock or con guration interaction approximations.

## A cknow ledgm ents

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APPENDIX A : FUNCTIONAL DER IVATIVES OF THE CONSTRAINT FUNC-TIONAL

In this Appendix we compute the functional derivative of the constraint functional. The constraint functional has the following form

$$Z$$
  
[]= dra(r) (j(r) I(r)): (A1)

The direct variation of the constraint functional with respect to the (r) yields:

$$\begin{array}{rcl} \hline \begin{bmatrix} 1 \\ 1 \end{bmatrix} &=& \begin{bmatrix} Z \\ Z \\ Z \\ \end{bmatrix} \begin{pmatrix} 1 \\ y \end{pmatrix} \begin{pmatrix} 1 \\$$

APPENDIX B:MATRIX ELEMENTS OF THE ANTI-COMMUTATOR [a (r);r],

The computation of the matrix element of the anti-commutator is presented below. The notation r  $^{a}$  m eans that the gradient acts on the Lagrange multiplier a (r) only.

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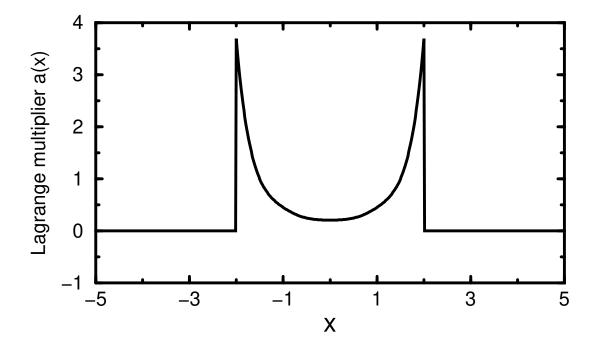
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Table 1. The energy of the active, is current carrying L x R, part of the system as a function of the steady current. E  $_{d} = E_{d}(I) = E_{d}(I = 0)$  is the energy increase to establish of the current I carrying state.

I	E <sub>d</sub> (I)	E <sub>d</sub> (I)
0.00	0.4977	0.0000
0.01	0.4994	0.0017
0.02	0.5043	0.0066
0.03	0.5124	0.0147
0.04	0 <b>.</b> 5233	0.0256
0.05	0.5368	0.0391
0.06	0.5526	0.0549
0.07	0.5706	0.0729
0.08	0.5905	0.0928
0.09	0.6122	0.1145
0.1	0.6356	0.1379

Figure 1. The Lagrange multiplier a(x) is plotted as a function of the coordinate x. Calculations were performed for the step function current density distribution j = 0:1 (x 2;2 x).



F igure 2. The spatial dependences of real and in aginary components of the current carrying wave function. Calculations were performed for the step function current density distribution j = 0.1 (x 2;2 x). The dashed line on the upper panel is the ground state wave function of the system with zero current.

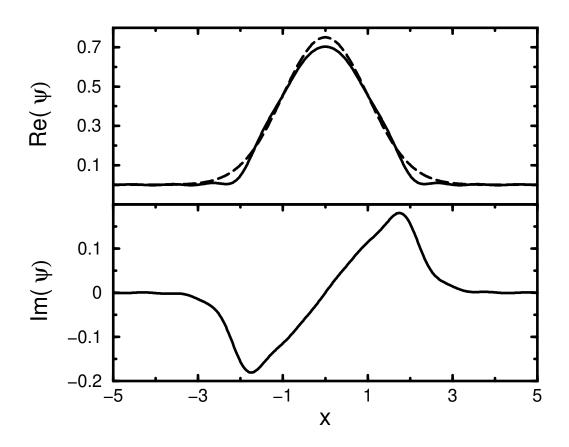


Figure 3. The spatial dependences of in aginary components of the wave functions are plotted for di erent values of the current. The current density is constrained to be the step function j = I (x 2;2 x). The solid line corresponds to I = 0.01, dotted to I = 0.05 and dashed to I = 0.1.

